Kramers doublets with total spin $S$ two molecules per cell. Its ground state presents two tem. This molecular complex forms a lattice which contains /H20851

St the synthesis of compounds with small dipolar interactions low-spin systems for quantum computation was addressed by /H20849

/H11011

hexagons with total spin $S$ Mn to keep quantum coherence. Together with the most famous polyoxovanadate compounds were extensively studied. 1,8–14

fundamental physics and possible applications like magnetic

attracted considerable interest for their implications in fun-

sical physics at low temperature. The fundamental proper-

sibly in intramolecular, hyperfine, and Dzyaloshinski-Moriya interactions. The values of intermolecular interactions were estimated to be $\theta \sim 10$ mK, obtained from the susceptibility behavior in the region where it follows a Curie-Weiss law $\chi = C/(T + \theta)$ $(C \sim 0.7\mu_B K/T)$. Thus, the exchange intramolecular interactions between V(IV) ions are dominant [Fig. 1(a)]: the main antiferromagnetic (AF) exchange interaction $J \sim 800$ K couples three pairs of spins inside the hexagons, while the remaining AF ones are inside the hexagon $(J' \sim 150$ K and $J'' \sim 300$ K) and between the hexagon and the triangle $(J_1 \sim 150$ K and $J_2 \sim 300$ K). 8–12 The AF exchange interaction between the spins in the triangle is very weak $(J_0 \sim 2.5$ K). With these interaction schemes, the first $S=5/2$ excited state lies 3.8 K above the $S=3/2$ ground state doublet. The successive excited $(S=3/2)$ state lies some hundreds of K above the ground state 8 [Fig. 1(b)]. The lowest-lying levels structure was confirmed by magnetization $M(H)$ and neutron scattering measurements, and new quantum effects were discovered.13,14 Particularly, for the sake of completeness it should be remarked that for constant $T<0.5$ K, at thermal equilibrium, $M(H)$ clearly exhibits a step at a critical field $H_c \sim 2.8$ T, where the $S=5/2$ ground state changes to $S=3/2$ (Ref. 9) (level crossing). On the other hand, nonequilibrium magnetization measurements with high-field sweeping rates revealed a “butterfly” hysteresis loop around zero magnetic field.9 These effects have been associated with phonon bottleneck and Dzyaloshinski-Moriya interaction.9,13,14

At variance with the possibilities of macroscopic techniques, NMR and muon-spin-rotation ($\mu$SR) use local probes to determine the microscopic behavior of local spins. With the aim of studying the local spin dynamics of V$^{4+}$ spins as a function of temperature $(0.3<T<300$ K) at constant fields and as a function of field at constant low $T$, we

Low-energy excitations in the $S=\frac{1}{2}$ molecular nanomagnet $K_6[V_{15}^{IV}As_6O_{42}(H_2O)] \cdot 8H_2O$ from proton NMR and $\mu$SR

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Zero- and longitudinal-field muon-spin-rotation ($\mu$SR) and $^1$H NMR measurements on the $S=\frac{1}{2}$ molecular nanomagnet $K_6[V_{15}^{IV}As_6O_{42}(H_2O)] \cdot 8H_2O$ are presented. In LF experiments, the muon asymmetry $P(t)$ was fitted by the sum of three different exponential components with fixed weights. The different muon relaxation rates $\lambda_i$ $(i=1,2,3)$ and the low-field $H=0.23$ T $^1$H NMR spin-lattice relaxation rate $1/T_1$ show a similar behavior for $T>50$ K: starting from room temperature they increase as the temperature is decreased. The increase of $\lambda_i$ and $1/T_1$ can be attributed to the “condensation” of the system toward the lowest-lying energy levels. The gap $\Delta \sim 550$ K between the first and second $S=\frac{3}{2}$ excited states was determined experimentally. For $T<2$ K, the muon relaxation rates $\lambda_i$ stay constant, independently of the field value $H \ll 0.15$ T. The behavior for $T<2$ K strongly suggests that, at low $T$, the spin fluctuations are not thermally driven but rather originate from quasielastic intramolecular or intermolecular magnetic interactions. We suggest that the very-low-temperature relaxation rates could be driven by energy exchanges between two almost degenerate $S=\frac{1}{2}$ ground states and/or by quantum effects.

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I. INTRODUCTION

The magnetic properties of molecular nanomagnets have attracted considerable interest for their implications in funda-

mental physics and possible applications like magnetic storage, magnetoelectronics, and quantum computing.1,2 These clusters are formed by identical mesoscopic magnetic entities, each one isolated from the others by a hydrophobic organic screen. Therefore the molecules act as individual quantum nanomagnets [single-molecule magnet (SMM)], enabling one to probe the crossover between quantum and classical physics at low temperature. The fundamental properties, such as, e.g., the ground-state spin, the magnetic anisotropy, and intramolecular and intermolecular interactions, can be determined accurately. Some of the newest and most striking phenomena observed at very low temperatures are the magnetic bistability, the quantum tunneling of the magnetization, quantum phase interference (Berry phase), quantum coherence, etc.2–6 Recently, the possibility of using low-spin systems for quantum computation was addressed by the synthesis of compounds with small dipolar interactions (a factor $10^{-3}$ lower than the high-spin systems) that allow one to keep quantum coherence. Together with the most famous Mn(12) (Refs. 1 and 2) and Fe(8) (Refs. 1 and 7) SMM’s, the polyoxovanadate compounds were extensively studied.1,8–14

Among them, the molecule $K_6[V_{15}^{IV}As_6O_{42}(H_2O)] \cdot 8H_2O$ [in short, V(15)] constitutes an example of a low-spin system. This molecular complex forms a lattice which contains two molecules per cell. Its ground state presents two Kramers doublets with total spin $S=\frac{1}{2}$, the doublets being split, in zero field, by $\sim 0.08$ K. This spin value is given by the arrangement of 15 V(IV) $s=\frac{1}{2}$ ions in three layers, two hexagons with total spin $S_b=0$ sandwiching a triangle with $S_c=\frac{1}{2}$.1,8–14 The origin of the ground-state splitting resides possibly in intramolecular, hyperfine, and Dzyaloshinki-Moriya interactions. The values of intermolecular interactions were estimated to be $\theta \sim 10$ mK, obtained from the susceptibility behavior in the region where it follows a Curie-Weiss law $\chi = C/(T+\theta)$ $(C \sim 0.7\mu_B K/T)$,13 Thus, the exchange intramolecular interactions between V(IV) ions are dominant [Fig. 1(a)]: the main antiferromagnetic (AF) exchange interaction $J \sim 800$ K couples three pairs of spins inside the hexagons, while the remaining AF ones are inside the hexagon ($J' \sim 150$ K and $J'' \sim 300$ K) and between the hexagon and the triangle ($J_1 \sim 150$ K and $J_2 \sim 300$ K).8–12 The AF exchange interaction between the spins in the triangle is very weak ($J_0 \sim 2.5$ K). With these interaction schemes, the first $S=\frac{3}{2}$ excited state lies 3.8 K above the $S=\frac{1}{2}$ ground-state doublet. The successive excited $(S=\frac{3}{2})$ state lies some hundreds of K above the ground state$^8$ [Fig. 1(b)]. The lowest-lying levels structure was confirmed by magnetization $M(H)$ and neutron scattering measurements, and new quantum effects were discovered.13,14 Particularly, for the sake of completeness it should be remarked that for constant $T<0.5$ K, at thermal equilibrium, $M(H)$ clearly exhibits a step at a critical field $H_c \sim 2.8$ T, where the $S=\frac{5}{2}$ ground state changes to $S=\frac{3}{2}$ (Ref. 9) (level crossing). On the other hand, nonequilibrium magnetization measurements with high-field sweeping rates revealed a “butterfly” hysteresis loop around zero magnetic field.9 These effects have been associated with phonon bottleneck and Dzyaloshinski-Moriya interaction.9,13,14

At variance with the possibilities of macroscopic techniques, NMR and muon-spin-rotation ($\mu$SR) use local probes to determine the microscopic behavior of local spins. With the aim of studying the local spin dynamics of V$^{4+}$ spins as a function of temperature $(0.3<T<300$ K) at constant fields and as a function of field at constant low $T$, we
performed μSR (in zero-field and longitudinal applied magnetic fields) and proton NMR experiments, with particular attention to the temperature behavior of the muon longitudinal and nuclear spin-lattice relaxation rates.

II. EXPERIMENTAL DETAILS

Microcrystalline samples of $K_{6}[V_{12}^{4+}As_{6}O_{42}(H_{2}O)] \cdot 8H_{2}O$ were prepared as described in Ref. 8. In order to characterize the magnetic properties of the sample, we performed magnetization measurements using a MPMS-XL7 Quantum Design magnetometer, in the temperature range 1.8–300 K at different constant magnetic fields $H=0.05, 0.15, 0.23,$ and $2.7$ T, corresponding to the fields used in μSR and NMR measurements.

The μSR data were collected at the ISIS facility, Rutherford Appleton Laboratory (UK), in the temperature range $0.3–300$ K, in zero field and longitudinal magnetic fields (LF) $H=0.05$ and $0.15$ T. Data at constant $T=0.34$ and $3.8$ K were also collected, in the LF range $0.05 \leq H \leq 0.3$ T. In LF-μSR experiments, the measured muon asymmetry $P(t)$ shows that the muon spin relaxes at any temperature and can be fitted using a sum of three different exponential components. This means that the muons implant in, at least, three different sites. By taking into account that the total asymmetry was $\sim 24$, after the usual background subtraction the function used to fit the data was

$$P(t) = a_1 \exp(-\lambda_1 t) + a_2 \exp(-\lambda_2 t) + a_3 \exp(-\lambda_3 t),$$

where $\lambda_1, \lambda_2,$ and $\lambda_3$ are muon longitudinal relaxation rates ($\lambda_1 > \lambda_2 > \lambda_3$) and $a_1 \sim 25\%, a_2 \sim 50\%,$ and $a_3 \sim 25\%$ their relative weights, kept constant for $0.05$ to $3.0$ T.

The results $(M/H) \times T$ for $H=0.15$ T vs temperature are reported in Fig. 2. It is noted that the qualitative behavior of the measured susceptibility is the same as the one reported previously$^8$ and that the variation in the quantity $(M/H) \times T$ with increasing field is small (data not reported). The current experimental results confirm the already known scheme and values of the exchange constants. The different μSR and NMR relaxation rates (RR’s) for $T>50$ K show qualitatively the same temperature behavior at $H \leq 0.23$ T [see Figs. 3(a) and 4]; starting from room temperature they increase as the temperature is decreased down to $T \sim 50(10)$ K. In the intermediate-temperature region $4<T<50$ K, μSR data follow the $(M/H) \times T$ behavior while proton NMR $1/T_1$ slightly increases on decreasing $T$. For $T<2$ K the muon relaxation rates stay constant within the experimental error and their value is almost independent of magnetic field. This is further confirmed by measurements at constant temperatures. At $T=0.34$ and $3.8$ K, the muon relaxation rates $\lambda_1$ stay constant for $0.05 \leq H \leq 0.2$ T [Fig. 3(b)]. At $T=0.34$ K, $\lambda_1$ and $\lambda_2$ have a slight decrease for fields $H>0.2$ T (data not reported). For $H=2.7$ T, $^1$H NMR
The magnetic fields were applied in the longitudinal direction. The analysis of the spin-lattice relaxation rates in V(15) powders, obtained from fit of the polarization data, see also Ref. 24, was limited by the intermolecular interaction Θ ∼ 10 mK, to fit the experimental data we finally assumed the expression 

$$\Gamma_0 = B + \Gamma_1 e^{-\Delta k_BT},$$

where $B=0.21 \times 10^9 \text{ rad Hz}$ is the intermolecular interaction frequency.

In this way the free parameters for fitting experimental data are $\Gamma_1$ and $\Delta$, while $A$ works as a rescaling factor and the $\chi T$ values used in Eq. (3) are the experimental ones extracted from superconducting quantum interference device (SQUID) data. The energy gap $\Delta$ between the two levels was determined by fitting the experimental $\Gamma_0$ vs $k_B T/\Delta$ NMR and $\mu$SR data, Fig. 5, in the range $k_B T/\Delta > 0.1$: we obtained $\Delta=551(3) \text{ K}$ and $\Gamma_1=\Gamma_{1\text{NMR}}=\Gamma_{1\text{\mu SR}}=0.226(0.028) \times 10^{11} \text{ rad Hz}$. By using these values in expression (5), with the formula (3) we fitted NMR data at $H=0.23 \text{ T}$ and $\mu$SR data at $H=0.05$ and $0.15 \text{ T}$, obtaining $A_{\text{NMR}}=8.5(1) \times 10^{12} \text{ rad^2 Hz^2/K}$ and $A_{\text{\mu SR}}(\lambda_2)=2.4(1) \times 10^{17} \text{ rad^2 Hz^2/K}$. It should be noted that $\Delta$ and $\Gamma_0$ are the same for NMR and $\mu$SR data. The fitting curves are reported in Fig. 6(a) (\mu SR).
and Fig. 6(b) (NMR). We chose $\lambda_2$ because statistically it is more significant as the muons stopping in the related site have the biggest relative weight in the total muon polarization.

We would like to remark that with our set of $T > 50$ K experimental data we were able to determine experimentally an estimate of the energy of the second excited $S = \frac{1}{2}$ level.

Noticeably it should be also remarked that $\Gamma(T)$ data for $T > 50$ K could be fitted as well with a power law of the form $\Gamma_0 = k T^{2.45}$ (fitting value $k = 1.7 \times 10^{11}$ rad Hz), in agreement with results on AF rings, grids, and high-spin clusters. So the exponential behavior and power law are indistinguishable in the temperature range chosen (see also Fig. 5). The existence of a single characteristic time $1/\Gamma_0$ that allows one to fit experimental data was recently confirmed by theoretical calculations starting from first principles. In Ref. 24, the characteristic time has an exponential behavior.

In the intermediate temperature region, $4 < T < 50$ K, the two-level scheme is no longer applicable, as the fine structure of the lowest-lying levels starts to become important. For this reason our model cannot be applied in this temperature region even though the $\mu$SR data qualitatively follow the theoretical fits, Eqs. (4).

Let us now briefly comment on the $\mu$SR relaxation rates for $T < 2$ K that stay constant independently of the muon implantation site and the applied magnetic field. This behavior indicates that, in this temperature region, the muon relaxation is possibly driven by quantum effects coming from frustration effects, with spin fluctuations whose frequencies do not depend on temperature and field. A second possibility is that $\lambda_i$ are driven by fluctuations of the total magnetization between the two lowest-lying $S = \frac{1}{2}$ doublets, whose energy difference is 0.08 K. The current set of experimental data is not sufficient to distinguish between the two hypotheses. In summary, in the low-spin system V(15), we determined experimentally the position of the second $S = \frac{1}{2}$ excited level by measuring, in the range $50 < T < 300$ K, the muon longitudinal relaxation rate $\lambda_2$ and the proton NMR spin-lattice relaxation rate. For $0.3 < T < 2$ K, the $\mu$SR longitudinal relaxation rates $\lambda_i$ are independent of field ($H \leq 0.15$ T) and temperature, thus suggesting quantum effects on the muon relaxation. The spin fluctuations that drive the muon relaxation can originate from the two $S = \frac{1}{2}$ ground-state doublets or from spin frustration.

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